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# Synthesis and optical properties of lead-free cesium germanium halide perovskite quantum rods†

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Herein, the fabrication of a lead-free cesium germanium halide perovskite produced via a simple solvothermal process is reported for the first time. By tuning the composition of the CsGeX<sub>3</sub> quantum rods, a power conversion efficiency of 4.92% under AM 1.5 G was achieved.

The global need for renewable and "green" energy alternatives continues to spur on research in low-cost and high-efficiency photovoltaic devices. Completely inorganic CsPbX<sub>3</sub> (X = I, Br, Cl) perovskites constitute one kind of perovskite material and have been considered to be probable substitutes for organicinorganic perovskites. 1,2 The hybrid, all-inorganic lead halide perovskites have generated enormous attention in the photovoltaic community due to their surprisingly rapid improvements in power conversion efficiency.<sup>3,4</sup> While recent investigations have been mostly focused on hybrid organicinorganic compounds, the study of their inorganic analogues, such as  $ABX_3$  (A = Rb, Cs; B = Ge, Sn, Pb; X = Cl, Br, I), has been limited.5 However, the lead component is toxic and hence of high concern for human health, and can cause environmental damage, particularly because of its chemical stability.6,7 By replacing the lead component with germanium at the B-site, a lead-free perovskite can be formed, obviating the pollution problems and hence being environmentally friendly. Replacing unsafe lead in perovskites is essential in order to expand their applications. As a result, there has been a great deal of interest in replacing lead with nontoxic metals such as tin, bismuth, and germanium.8-10

Over the past several years, considerable advances have been made toward the synthesis of colloidal semiconductor nanorods or nanofibers with diameters sufficiently small to produce a quantum confinement of charge carriers. Semiconductor quantum rods (QRs) show properties between zero-dimensional quantum dots (QDs) and one-dimensional quantum wires. Per unit mass, QR volumes are larger than QD volumes and therefore have significantly larger per-particle absorbance cross sections. This feature would be expected to increase the optical density of electrodes covered by up to a single layer of QR nanoparticles and therefore improve light harvesting. QRs are

great advantages such as low cost and flexibility.20-22 In this research we demonstrated a simple, rapid, and green solvothermal synthesis of high-quality lead-free perovskite-type CsGeX<sub>3</sub> with a uniform QR-shaped structure, and found the use of this material to enhance photovoltaic efficiency. To our knowledge, this work is the first example of a solvothermal synthesis of high-quality CsGeX<sub>3</sub> QRs with finely tunable PL and uniform diameters, and yielding high-performance solar cells showing efficiency levels up to 11%. As shown in Fig. 1, the optical absorbance and photoluminescence of all the tested inorganic perovskite quantum rods were red-shifted to longer wavelengths because of the confinement of the halide.23 The QR exhibited typically sharp absorption onsets, similar to those of the bulk dispersion. The slight shift of the first transition to longer wavelengths, when comparing CsGeCl3 to CsGeI3, might have been caused by a slight change in the lattice constant. Although a red shift in the absorption band was found for CsGeX3 (starting from Cl to Br to I), a 90 nm shift in the absorption onset (from 565 to 655 nm) was observed when the halide (Cl or Br or I) was used in the

formation of CsGeX3 under similar conditions. Moreover, the

overall intensity of the absorption band was altered. As such,

the addition of different amounts of Br and I seemed to affect the optical properties of the perovskite composites. With the increased ratio of the amount of Br to the amount of I, the light

absorption of the perovskite quantum rods in the visible-light

range was gradually enhanced. This good agreement indicated

of great interest for fundamental research and are highly promising novel materials for new technologies. 15,16 However,

QR properties also depend on the quality of their internal

crystal structure and may also exhibit decreased Auger recom-

bination rates compared to those of quantum dots,17 which

makes them potentially useful for advanced optoelectronic

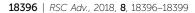
devices. Many modern methods have been developed for the synthesis of one-dimensional QRs. 18,19 However, these prepa-

ration processes often require a relatively high temperature and

vacuum, are complex, etc., while solvothermal methods offer

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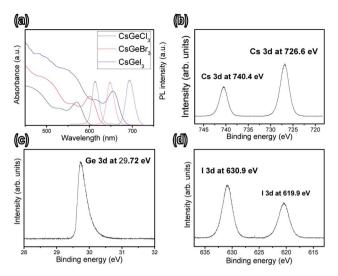


Fig. 1 (a) Optical absorption and photoluminescence spectra of  $CsGeX_3$  (X = Cl, Br and I). (b-d) XPS spectra of  $CsGeI_3$  in the (b) Cs 3d, (c) Ge 3d and (d) I 3d regions.

the halide improvement to be primarily resulting from the enhanced absorption due in turn to the lattice constant with larger atoms. When excited by light with a wavelength of 532 nm, the wavelength of the photoluminescence emission from the QRs could be tuned from 607 to 696 nm with a full width at half-maximum (FWHM) of about 25 nm.

The surface chemistry of CsGeX3 was investigated by X-ray photoemission spectroscopy (XPS) in Fig. 1b-d. Analysis of these spectra indicated the presence of Cs, Ge, and I, and hence demonstrated the high purity of the as-synthesized CsGeI<sub>3</sub> quantum rods. Two distinct peaks appeared at 726.6  $(2p_{3/2})$  and 740.4 eV  $(2p_{1/2})$ , i.e., with a binding energy splitting of 13.8 eV. These observations were consistent the presence of Cs.<sup>24</sup> A peak was also observed at 29.72 ( $3d_{5/2}$ ). This peak was attributed to Ge 3d, confirming the Ge state.<sup>25</sup> In addition, peaks were observed at 619.9 and 630.9 eV. These peaks were attributed to I 3d<sub>5/2</sub>, and were in good agreement with values reported for the oxidation state of halides.26 These results taken together demonstrated that CsGeI3 quantum rods were successfully synthesized. Fig. S1<sup>†</sup> shows the time-resolved PL decay curve of the CsGeX<sub>3</sub> quantum rods. PL decay dynamics were recorded with 50 µW of 3.0 eV photons produced by a 35 fs, 2 kHz Ti:sapphire laser. The mean maximum-intensity lifetimes for samples CsGeCl<sub>3</sub>, CsGeBr<sub>3</sub>, and CsGeI<sub>3</sub> were 16.8, 18.6, and 20.4 ns respectively, and corresponded to the previously reported radiative relaxation time of excitons associated with the hybrid perovskite nanocrystals.27 For the CsGeI3 quantum rods, the longest lifetimes were over 24.2 ns, significantly longer than the lifetimes typically observed for other perovskite hybrid quantum rods. We suggest that this observation resulted from halide atom inhomogeneity (i.e., in atomic weight) and exciton radiative recombination in the small nanocrystals.28,29

Fig. 2a displays a transmission electron microscopy (TEM) image of the perovskite CsGeI<sub>3</sub> quantum rods. Inspection of this image revealed the microscopic morphology and structural information of the composite, specifically that this perovskite

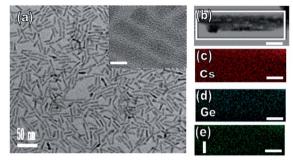


Fig. 2 (a) Typical high-resolution TEM image of the perovskite  $CsGel_3$  quantum rods. Inset shows a selected magnified TEM image of several QRs. (b) TEM image of the obtained perovskite quantum rods and (c-e) corresponding energy dispersive spectroscopy (EDS) elemental mapping images, specifically for (c) Cs, (d) Ge, and (e) I. These images confirmed that Cs, Ge, and I were sequentially and uniformly deposited onto the entire surface of each of the  $CsGel_3$  quantum rods on a copper grid. The scale bar is 5 nm.

sample formed rod-like structures. Fig. 2a inset shows an HRTEM image of individual CsGeI<sub>3</sub> quantum rods. Inspection of this image revealed a crystalline structure with observed lattice spacings of 0.58 and 0.56 nm, corresponding, respectively, to the (110) and (200) planes of perovskite CsGeI<sub>3</sub>. In the PL spectra of all of the perovskite quantum rods, the PL emission bands were significantly enhanced compared to that of the CsGeX<sub>3</sub> quantum rods, which demonstrated that increasing the atomic weight effectively passivated the defects on the surface of the CsGeX<sub>3</sub>.30 Moreover, the PL intensity increased and red shifted with increasing atomic weight. As the atomic weight was increased from that of Cl to that of I, the intensity of the PL emission was observed to increase. Furthermore, the PL emission band for CsGeI3 was slightly red shifted relative to that for CsGeCl<sub>3</sub>, indicating that the size distribution of the CsGeX<sub>3</sub> quantum rods increased during the solvothermal process. On the other hand, the CsGeI3 quantum rods showed very good crystallinity, a benefit for PL performance. However, compositional analysis of the quantum rods using XPS showed a molar Cs/Ge/X (X = Cl, Br, and I) ratio of 1 : 1 : 3. Analysis of individual particles using EDS also showed a ratio of 1:1:3, with a variation from particle to particle of less than the approximately  $\pm 2$ atom% experimental error (see Table S1†). Accordingly, the continuity of the fiber suggested the high quality of our CsGeX<sub>3</sub> quantum rods. Moreover, measurements taken from 150 quantum rods in our sample revealed them to have an average diameter of about 5 nm, with a deviation of about 15-18%, which indicated the high quality of our samples. Additionally, the typical rods had lengths of several tens of nanometers. Fig. 2b-e show Cs, Ge, and I elemental mappings of the CsGeI<sub>3</sub> quantum rods obtained via TEM energy-dispersive X-ray spectroscopy (EDS). Analysis of these images indicated the formation of ternary perovskite CsGeI<sub>3</sub> quantum rods consisting of Cs (red), Ge (blue), and I (green) distributed throughout the quantum rod. The quantitative EDS analysis of a CsGeI3 quantum rod indicated a Cs: Ge: I atomic ratio of about 0.96: 0.94: 2.85, quite close to the nominal 1:1:3 ratio given by stoichiometry of the precursor solutions. This result clearly

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showed the quantum rod to be mainly composed of CsGeI3. Similar quantitative results were also obtained from EDS measurements (SEM) and X-ray photoelectron spectroscopy (XPS) analysis (Table S1†). Further experiments were also performed to estimate the film stability under various conditions (Fig. S2†). We took absorbance measurements of the CsGeI<sub>3</sub> and CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> perovskite films under the same conditions. When CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> films were exposed to air for a period of time, the intensity of the absorption edge rapidly decreased after 2 h, and the edge completely disappeared after 15 h (Fig. S2:† black), indicating the decomposition of the perovskite structure. The color of the film also correspondingly changed from dark red to light brown within 3 h (inset of Fig. S2†), which implied the disintegration of the perovskite structure. Our simple strategy can be extended to other perovskite systems for improving their stability. Under the same conditions, the CsGeI<sub>3</sub> perovskite film showed a slow decomposition (i.e., an approximately 45% decomposition in 48 h), whereas the CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> film showed a rapid degradation (i.e., 98% decomposition in less than 24 h).

Fig. 3a shows typical current density-voltage (I-V) curves for completely inorganic lead-free perovskite solar cells with the different halides (Cl, Br, or I), and the curves were obtained in the presence of different concentrations of halide under air mass (AM) 1.5 G solar irradiation; the photovoltaic parameters are summarized in Table S2.† The best solar cell performance was measured when using the CsGeI3 quantum rod perovskite, and showed a short-circuit current density  $(J_{sc})$  of 18.78 mA cm<sup>-2</sup>, open-circuit voltage  $(V_{oc})$  of 0.51 V, fill factor (FF) of 0.51, and the power conversion efficiency (PCE) of 4.94%. The best solar cell using the CsGeBr3 quantum rod perovskite showed a  $J_{\rm sc}$  of 19.49 mA cm<sup>-2</sup>,  $V_{\rm oc}$  of 0.48 V, FF of 0.52, and PCE of 4.92%. And the best solar cell using CsGeCl<sub>3</sub> quantum rods showed a  $J_{\rm sc}$  of 18.57 mA cm $^{-2}$ ,  $V_{\rm oc}$  of 0.35 V, FF of 0.40, and PCE of 2.57%. That is, the solar cell PCE was lowest when its perovskite included the halide with the lowest atomic volume, *i.e.*, Cl. This decrease was primarily the result of the reduced  $J_{sc}$ , Voc, and FF. The IV and PCE values of the CsGeI<sub>3</sub> and CsGeBr<sub>3</sub> were better than the values measured for CsGeCl<sub>3</sub>, demonstrating the benefits of CsGeI3 as an absorber material. Note that a Cs: : Ge: I molar ratio of 1: 0.92: 2.52 molar ratio in the device was found to be optimum for device performance (see Table S2, ESI†). A group of devices, with five devices for each composition tested, was fabricated in order to further explain the relationship between device performance and halide ratio. Performance statistics for the lead-free perovskite quantum rod solar cells are provided in Fig. S3 of the ESI;† these cells showed excellent reproducibility with an average efficiency of 3.57%  $\pm$ 0.5%. From these studies, we concluded that including the indicated amount of I precursor improved all of the photovoltaic parameters. In addition, perovskite crystallinity has been shown to influence the ultimate performance of the constructed device, with this influence attributed to defects in the crystals forming shorting and trapping sites for charge recombination. Crystallinity has also been shown to very much influence charge transport, separation, and diffusion length.31,32 Solar cells with high FF values have been shown to display active charge transfer and extraction from their planar

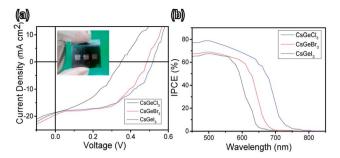


Fig. 3 (a) J-V characteristics of  $CsGel_3$  (blue),  $CsGeBr_3$  and  $CsGeCl_3$  (red, and black) solar cells. The inset shows a photograph of the flexible device. (b) IPCE of  $CsGeX_3$  perovskite devices with different halide ratios. The photovoltaic results are summarized in Table S2.†

heterojunctions.<sup>33</sup> The resulted in the greater efficiency of the device formed on quantum rods, which motivated us to explore the influence of our solvothermal method on this facile system. The external quantum efficiency (EQE) plotted in Fig. 3b confirms the increased  $J_{sc}$  values of these devices, in which the merged  $J_{sc}$  values for the devices derived from lead-free perovskites CsGeI<sub>3</sub>, CsGeBr<sub>3</sub> and CsGeCl<sub>3</sub> were determined to be 11.08, 10.22, and 9.15%, respectively. The maximum EQE values of the top-performing devices were observed to exceed 66% (for CsGeCl<sub>3</sub>), 68% (for CsGeBr<sub>3</sub>) and 79% (for CsGeI<sub>3</sub>). We plan to investigate the use of the completely inorganic lead-free quantum rods as absorber materials in perovskite solar cells; we plan to do so since these rods may improve the cell characteristics due to their low cost, low toxicity, high chemical and photo-stabilities, and good thermal effects, compared to organic composites.34 The is expected to increase the optical density of active layer and therefore improve light harvesting. Furthermore, the surface areas of quantum rods are greater than those of the bulk material, which may allow for greater contact areas and hence improve the conversion efficiency. The resulted can further improve charge separation efficiency, leading to higher performance of the perovskite solar cells.

#### Conclusions

 $CsGeX_3$  (X = Cl, Br, and I) with tunable emission wavelengths ranging from 607 to 696 nm have been prepared through a versatile and relatively inexpensive technique involving the use of composite quantum rods under different halide salt conditions. In this work, we found that the optical properties of the completely inorganic lead-free perovskites can be altered without annealing by using a solvothermal process, which makes them attractive for novel optoelectronic devices. Highquality lead-free perovskite quantum rods with compositiontunable emission have been synthesized using a simple solvothermal synthetic approach. Emission wavelengths spanning the visible spectrum could be facilely tuned by altering the composition of the halide salts. Finally, a remarkable enhancement in the photovoltaic performance of the CsGeX3 devices, specifically with power conversion efficiency values close to 4.94%, was realized. We fully expect this work to contribute to a fundamental understanding of the structural,

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morphological and optical properties of lead-free halide perovskite quantum rods. We also expect these rods to be useful for inexpensive nontoxic optical materials, light absorbers for solar cells, or other electric devices, LEDs, and biosensor materials.

### Conflicts of interest

There are no conflicts to declare.

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